

4th Generation 1200 V, 30 A Silicon Carbide Schottky Diode

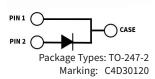
Description

With the performance advantages of a Silicon Carbide (SiC) Schottky Barrier diode, power electronics systems can expect to meet higher efficiency standards than Si-based solutions, while also reaching higher frequencies and power densities. SiC diodes can be easily paralleled to meet various application demands, without concern of thermal runaway. In combination with the reduced cooling requirements and improved thermal performance of SiC products, SiC diodes are able to provide lower overall system costs in a variety of diverse applications.









Features

- Low Forward Voltage (V_F) Drop with Positive Temperature Coefficient
- Zero Reverse Recovery Current / Forward Recovery Voltage
- Temperature-Independent Switching Behavior

Typical Applications

- Industrial Switched Mode Power Supplies
- Uninterruptible & AUX Power Supplies
- Boost for PFC & DC-DC Stages
- Solar Inverters

Maximum Ratings ($T_c = 25^{\circ}$ C Unless Otherwise Specified)

Parameter	Symbol	Value	Unit	Test Conditions	Notes	
Repetitive Peak Reverse Voltage	V _{RRM}	1200	V			
DC Blocking Voltage	V _{DC}	1200	V			
		94		T _c = 25 °C		
Continuous Forward Current	I _F	45		T _c = 135 °C	Fig. 3	
		30	А	T _c = 155 °C		
Repetitive Peak Forward Surge Current	I _{FRM}	121		T _c = 25 °C, t _p = 10 ms, Half Sine Wave		
		68		$T_c = 110 ^{\circ}\text{C}, t_p = 10 \text{ms}, Half Sine Wave}$		
Non-Repetitive Forward Surge		233		T _c = 25 °C, t _p = 10 ms, Half Sine Wave	F:~ 0	
Current	FSM	209		$T_c = 110 ^{\circ}\text{C}, t_p = 10 \text{ms}, \text{Half Sine Wave}$	Fig. 8	
i²t Value	∫i²t	271		$T_{c} = 25 ^{\circ}\text{C}, t_{D} = 10 \text{ms}$		
		218		$T_c = 110 {}^{\circ}\text{C}, t_p = 10 \text{ms}$		
Power Dissipation	P _{tot}	441	W	T _c = 25 °C	Fig. 4	
		191		T _c = 110 °C		

Electrical Characteristics

Parameter	Symbol	Тур.	Max.	Unit	Test Conditions	Notes	
Forward Voltage	V	1.5	1.8	V	I _F = 30 A, T _j = 25 °C	Fig. 1	
	V _F	2.2	3		I _F = 30 A, T _j = 175 °C	Fig. 1	
Reverse Current		40	250	μA	$V_R = 1200 \text{ V}, T_j = 25 \text{ °C}$	- Fig. 2	
	I _R	70	450		$V_R = 1200 \text{ V}, T_j = 175 \text{ °C}$		
Total Capacitive Charge	Q _c	152		nC	$V_R = 800 \text{ V, T}_j = 25 \text{ °C}$	Fig. 5	
		2177			$V_R = 0 \text{ V}, T_j = 25 \text{ °C}, f = 1 \text{ MHz}$		
Total Capacitance	С	136		pF	$V_R = 400 \text{ V}, T_j = 25 \text{ °C}, f = 1 \text{ MHz}$	Fig. 6	
		100			V _R = 800 V, T _j = 25 °C, f = 1 MHz		
Capacitance Stored Energy	E _c	44		μJ	V _R = 800 V	Fig. 7	

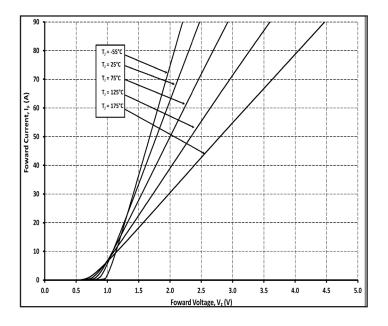
Notes:

SiC Schottky Diodes are majority carrier devices, so there is no reverse recovery charge.

Thermal & Mechanical Characteristics

Parameter	Symbol	Value	Unit	Notes
Thermal Resistance, Junction to Case (Typical)	R _{0, JC (TYP)}	0.34	°C/W	
Junction Temperature	T _j	-55 to +175	- °C	
Case & Storage Temperature	T _c	-55 to +150		
TO 247 Manusting Tayana		1	Nm	M3 Screw
TO-247 Mounting Torque	-	8.8	lbf-in	6-32 Screw

Typical Performance



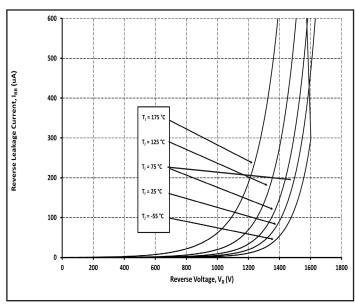
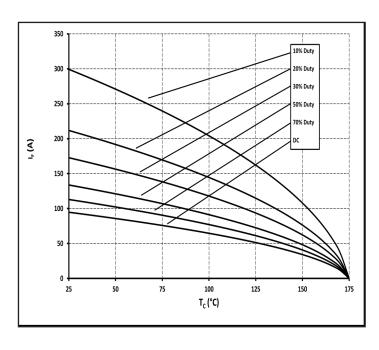


Figure 1. Forward Characteristics

Figure 2. Reverse Characteristics



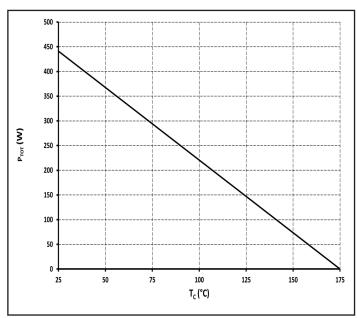
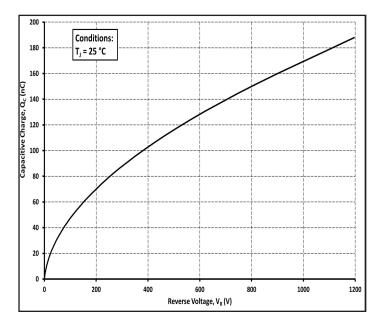


Figure 3. Current Derating

Figure 4. Power Derating

Typical Performance



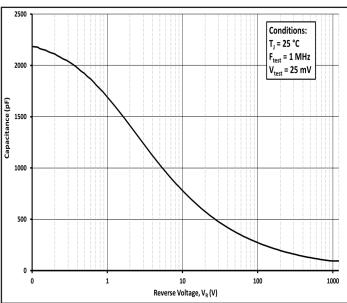
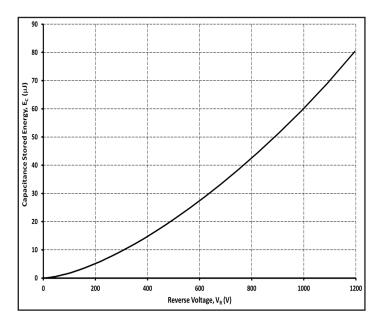


Figure 5.
Total Capacitance Charge vs. Reverse Voltage

Figure 6.
Capacitance vs. Reverse Voltage



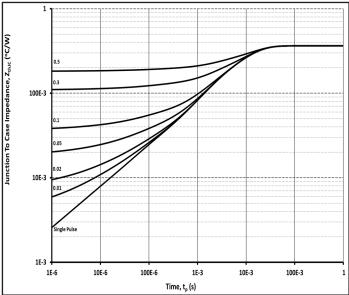
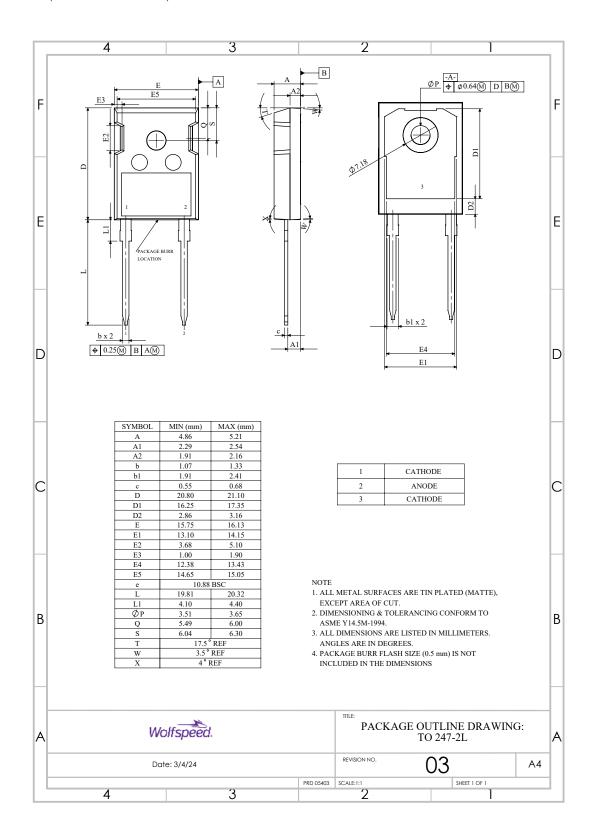


Figure 7.
Typical Capacitance Stored Energy

Figure 8. Transiant Thermal Impedence

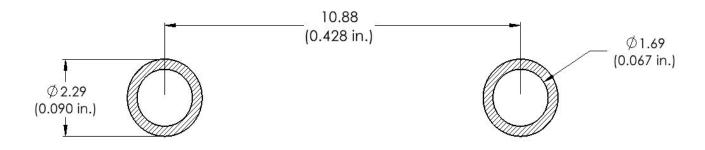
Package Dimensions & Pin-Out

Package: TO-247-2 (All dimensions are in mm)



Recommended Solder Pad Layout

(All dimensions are in mm)



Product Ordering Information

Order Number	Packing Type
C4D30120H	Tube

REACh, RoHS, and Halogen-Free compliance documentation available for this product.

Revision History

Document Version	Date of Release	Description of changes
0	January - 2019	Initial Release
1	January - 2023	Updated POD and Landing Pad
2	August - 2024	Notes and dislaimers, added ROHS and Halogen Free Symbols

Notes & Disclaimer

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